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TS5A3159A

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TS5A3159A 1Ω SPDT 模拟开关 5V 和 3.3V 单通道 2:1 多路复用器和多路解复用器

1 特性

- 额定的先断后合开关
- 断电模式中的隔离, $V_+ = 0$
- 与 TS5A3159 器件终端兼容
- 低导通状态电阻 (1Ω)
- 控制输入可承受 5.5V 电压
- 低电荷注入
- 出色的导通电阻匹配
- 低总谐波失真 (THD)
- 1.65V 至 5.5V 单电源运行
- 闩锁性能超过 100mA, 符合 JESD 78 II 类规范
- ESD 性能测试符合 JESD 标准
 - 2000V 人体放电模式 (A114-B, II 类)
 - 1000V 充电器件模型 (C101)

2 应用

- 手机
- 掌上电脑 (PDA)
- 便携式仪表
- 音频和视频信号路由
- 低电压数据采集系统
- 通信电路
- 调制解调器
- 硬盘
- 计算机外设
- 无线终端和外设

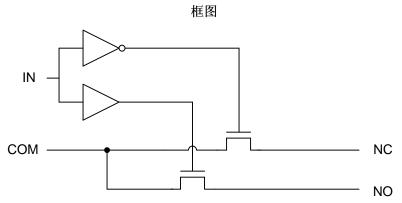
3 说明

TS5A3159A 器件是单极双投 (SPDT) 模拟开关,设计的工作电压为 1.65V 至 5.5V。该器件提供低导通电阻和出色的导通电阻匹配以及先断后合功能,能够防止信号从一个通道传输至另一通道时失真。此器件具有出色的总谐波失真 (THD) 性能并且能耗极低。这些 特性 使得这款器件适合于便携式音频 应用。

器件信息(1)

| 器件型号 | 封装 | 封装尺寸 (标称值) |
|---------------|------------|-----------------|
| TS5A3159ADBVR | SOT-23 (6) | 2.90mm x 1.60mm |
| TS5A3159ADCKR | SC70 (6) | 2.00mm × 1.25mm |
| TS5A3159AYZPR | DSBGA (6) | 1.41mm × 0.91mm |

(1) 如需了解所有可用封装,请参阅产品说明书末尾的可订购产品 附录。



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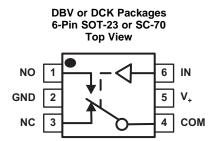
4 修订历史记录

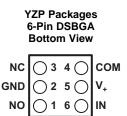
注: 之前版本的页码可能与当前版本有所不同。

Changes from Revision E (November 2015) to Revision FPage• Changed the YZP package From: 8 Pins To: 6 Pins in the Thermal Information table4Changes from Revision D (June 2015) to Revision EPage• Changed Pin Descriptions3Changes from Revision C (May 2010) to Revision DPage• 已添加应用、器件信息表、引脚功能表、ESD 额定值表、热性能信息表、典型特性、特性 说明 部分、器件功能模式、应用和实施 部分、电源建议 部分、布局 部分、器件和文档支持 部分以及机械、封装和可订购信息 部分。1



5 Pin Configuration and Functions





NO – Normally open NC – Normally closed

Pin Functions

| | PIN | | | | |
|------|------------------|-------|-----|--|--|
| NAME | SOT-23, SC-70 | DSBGA | I/O | DESCRIPTION Common switch a set | |
| COM | 4 | C2 | I/O | Common switch port | |
| GND | 2 | B1 | _ | Ground | |
| IN | 6 | A2 | I/O | Switch select. High = COM connected to NO; Low = COM connected to NC | |
| NC | 3 | C1 | I/O | Normally closed switched port | |
| NO | 1 | A1 | _ | Normally open switch port | |
| V+ | 5 | B2 | I | Power supply | |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)

| | | | MIN | MAX | UNIT |
|--|--|-------------------------------------|------|----------------------|------|
| V ₊ | Supply voltage (3) | | -0.5 | 6.5 | V |
| V _{NO} , V _{NC} , V _{COM} | Analog voltage (3)(4)(5) | | -0.5 | V ₊ + 0.5 | V |
| I _K | Analog port diode current | V_{NC} , V_{NO} , $V_{COM} < 0$ | -50 | | mA |
| INO, | ON-state switch current | | -200 | 200 | mA |
| | ON-state peak switch current ⁽⁶⁾ V_{NO} , V_{NC} , $V_{COM} = 0$ to V_{+} | | -400 | 400 | mA |
| VI | Digital input voltage (3) (4) | | -0.5 | 6.5 | V |
| I _{IK} | Digital input clamp current | V _I < 0 | -50 | | mA |
| I ₊ | Continuous current through V ₊ | | | 100 | mA |
| I _{GND} | Continuous current through GND | | -100 | 100 | mA |
| _ | About to mark the control of the con | DBV or DCK package | | 150 | °C |
| T _A | Absolute maximum operating temperature (7) | YZP package | | 125 | -0 |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
- 3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration <10% duty cycle.
- (7) The lifetime of the device will be reduced if the device operates continually at this temperature.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±2000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±1000 | V |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|------------------|-----------------------------|------|----------------|------|
| V _{I/O} | Switch input/output voltage | 0 | V ₊ | V |
| V+ | Supply voltage | 1.65 | 5.5 | V |
| VI | Control input voltage | 0 | 5.5 | V |
| T _A | Operating temperature | -40 | 85 | °C |

6.4 Thermal Information

| | | TS5A3159A | | | | |
|----------------|--|--------------|-------------|-------------|------|--|
| | THERMAL METRIC ⁽¹⁾ | DBV (SOT-23) | DCK (SC-70) | YZP (DSBGA) | UNIT | |
| | | 6 PINS | 6 PINS | 6 PINS | | |
| R_{\thetaJA} | Junction-to-ambient thermal resistance | 165 | 259 | 123 | °C/W | |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics for 5-V Supply

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

| P | ARAMETER | TEST CONDI | TIONS | T _A | V ₊ | MIN | TYP | MAX | UNIT |
|--|---------------------------|--|--|----------------|----------------------|------|------|----------------|------|
| ANALOG SWIT | СН | | | | | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal | | | | | 0 | | V_{+} | V |
| | Dools ON registeres | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ | Switch on, | 25°C | 45.1/ | | 0.8 | 1.1 | ^ |
| r _{peak} | Peak ON resistance | $I_{COM} = -100 \text{ mA},$ | see Figure 14 | Full | 4.5 V | | | 1.5 | Ω |
| _ | ON state registeres | V_{NO} or $V_{NC} = 2.5 \text{ V}$, | Switch on, | 25°C | 45. | | 0.7 | V ₊ | |
| r _{on} | ON-state resistance | $I_{COM} = -100 \text{ mA},$ | see Figure 14 | Full | 4.5 V | | | 1.1 | Ω |
| Ar | ON-state resistance | V_{NO} or $V_{NC} = 2.5 \text{ V}$, | Switch on, | 25°C | 4.5 V | | 0.05 | 0.1 | Ω |
| $\Delta r_{\sf on}$ | match between channels | $I_{COM} = -100 \text{ mA},$ | see Figure 14 | Full | 4.5 V | | | 0.1 | 12 |
| | ON-state resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$ | Switch on, see Figure 14 | 25°C | | | 0.15 | | |
| r _{on(flat)} | flatness | V_{NO} or $V_{NC} = 1 \text{ V}, 1.5 \text{ V}, 2.5 \text{ V},$ | Switch on, | 25°C | 4.5 V | | 0.1 | 0.25 | Ω |
| | | $I_{COM} = -100 \text{ mA},$ | see Figure 14 | Full | | | | 0.25 | |
| | | V_{NC} or $V_{NO} = 1 \text{ V}$, $V_{COM} = 1 \text{ V}$ | 0 '' 1 " | 25°C | | -20 | 2 | 20 | |
| I _{NC(OFF)} , I _{NO(OFF)} | NC, NO | to 4.5 V, or V_{NC} or V_{NC} or V_{NC} = 4.5 V, V_{COM} = 1 V to 4.5 V, | Switch off, see Figure 15 | Full | 5.5 V | -100 | | 100 | nA |
| I _{NC(PWROFF)} , | OFF leakage current | V_{NC} or $V_{NO} = 0$ to 5.5 V, | Switch off, | 25°C | | -1 | 0.2 | 1 | |
| I _{NO(PWROFF)} | | $V_{COM} = 5.5 \text{ V to } 0,$ | see Figure 15 | Full | 0 V | -20 | | 20 | μΑ |
| 1 | NC, NO | V_{NC} or $V_{NO} = 1 V$, | Switch on, | 25°C | | -20 | 2 | 20 | |
| I _{NC(ON)} , I _{NO(ON)} | ON leakage current | V_{COM} = Open, or V_{NC} or V_{NO} = 4.5 V, V_{COM} = Open, | see Figure 16 | Full | 5.5 V | -100 | | 100 | nA |
| | COM | V_{NC} or $V_{NO} = 0$ to 5.5 V, | Switch off, | 25° | 0.14 | -1 | 0.1 | 1 | |
| COM(PWROFF) | OFF leakage current | $V_{COM} = 5.5 \text{ V to } 0,$ | see Figure 15 | Full | 0 V | -20 | | 20 | μΑ |
| | COM | V _{NC} or V _{NO} = Open, | Switch on, | 25°C | | -20 | 2 | 20 | |
| I _{COM(ON)} | ON leakage current | $V_{COM} = 1 \text{ V, or } V_{NC} \text{ or } V_{NO} = 0 \text{ Open, } V_{COM} = 4.5 \text{ V,}$ | see Figure 16 | Full | 5.5 V | -100 | | 100 | nA |
| DIGITAL INPUT | (IN) | | | | | | | | |
| V _{IH} | Input logic high | | | Full | | 2.4 | | 5.5 | V |
| V _{IL} | Input logic low | | | Full | | 0 | | 8.0 | • |
| I _{IH} , I _{IL} | Input leakage current | V _I = 5.5 V or 0 | | 25°C | 5.5 V | -2 | | 2 | nA |
| יוחי יוב | put lounage outom | 1, 0.0 1 0.0 | | Full | | 100 | | 100 | |
| DYNAMIC | | | | 25°C | 5 V | 1 | 12 | 30 | |
| t _{ON} | Turnon time | $V_{COM} = V_+,$ $R_L = 50 \Omega,$ | C _L = 35 pF, see Figure 18 | Full | 4.5 V to 5.5 V | 1 | | 35 | ns |
| | | | | 25°C | 5 V | 1 | 5 | 20 | |
| t _{OFF} | Turnoff time | $V_{COM} = V_{+},$ $R_{L} = 50 \Omega,$ | C _L = 35 pF, see Figure 18 | Full | 4.5 V to 5.5 V | 1 | | 30 | ns |
| | | | | 25°C | 5 V | | 6 | | |
| t _{BBM} | Break-before-make time | $\begin{aligned} V_{NC} &= V_{NO} = V_+, \\ R_L &= 50 \ \Omega, \end{aligned}$ | C _L = 35 pF, see Figure 19 | Full | 4.5 V to 5.5 V | 1 | | 20 | ns |
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, see Figure 23 | 25°C | 5 V | | -20 | | pC |
| C _{NC(OFF)} , C _{NO(OFF)} | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch off, see Figure 17 | 25°C | 5 V | | 18 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch on, see Figure 17 | 25°C | 5 V | | 55 | | pF |
| C _{COM(ON)} | COM ON capacitance | V _{COM} = V ₊ or GND, | Switch on, see Figure 17 | 25°C | 5 V | | 55 | | pF |
| C _I | Digital input capacitance | $V_I = V_+ \text{ or GND},$ | See Figure 17 | 25°C | 5 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, | Switch on, see Figure 20 | 25°C | 5 V | | 100 | | MHz |
| | | 1 | | 1 | 1 | 1 | | | |

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.



Electrical Characteristics for 5-V Supply (continued)

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST C | CONDITIONS | TA | V ₊ | MIN TYP | MAX | UNIT |
|-------------------|---------------------------|--|--|------|----------------|---------|-----|------|
| O _{ISO} | Off isolation | $R_L = 50 \Omega$, f = 1 MHz, | Switch off, see Figure 21 | 25°C | 5 V | -64 | | dB |
| X _{TALK} | Crosstalk | $R_L = 50 \Omega$, f = 1 MHz, | Switch on, see Figure 22 | 25°C | 5 V | -64 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega,$ $C_L = 50 \text{ pF},$ | f = 200 Hz to 20 kHz, see Figure 24 | 25°C | 5 V | 0.004% | | |
| SUPPLY | | | | | | | | |
| | Positive supply current | $V_1 = V_+$ or GND, | Switch on or off | 25°C | 5.5 V | 10 | 50 | nA |
| '+ | Fositive supply current | $v_1 = v_+$ or GND, | Switch on or or | Full | 5.5 V | | 500 | |

6.6 Electrical Characteristics for 3.3-V Supply

 $V_{+} = 3 \text{ V}$ to 3.6 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

| | PARAMETER | TEST COND | ITIONS | T _A | V ₊ | MIN | TYP | MAX | UNIT |
|---|-------------------------------|---|-----------------------------|----------------|-----------------|------|------|----------------|------|
| ANALOG SW | ITCH | | | 1 | • | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V ₊ | V |
| r | Peak ON resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ | Switch on, | 25°C | 3 V | | 1.3 | 1.6 | Ω |
| r _{peak} | reak ON resistance | $I_{COM} = -100 \text{ mA},$ | See Figure 14 | Full | 3 V | | | 2 | 12 |
| r _{on} | ON-state resistance | V_{NO} or $V_{NC} = 2 V$, | Switch on, | 25°C | 3 V | | 1.2 | 1.5 | Ω |
| on | On state resistance | $I_{COM} = -100 \text{ mA},$ | See Figure 14 | Full | | | | 1.7 | |
| Δr_{on} | ON-state resistance match | V_{NO} or $V_{NC} = 2 V$, 0.8 V, | Switch on, | 25°C | 3 V | | 0.1 | 0.15 | Ω |
| on | between channels | $I_{COM} = -100 \text{ mA},$ | See Figure 14 | Full | | | | 0.15 | |
| _ | ON-state resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$ | Switch on, See Figure 14 | 25°C | 3 V | | 0.2 | | |
| r _{on(flat)} | flatness | V_{NO} or $V_{NC} = 2 V$, 0.8 V, | Switch on, | 25°C | 3 V | | 0.15 | 0.3 | Ω |
| | 1 | $I_{COM} = -100 \text{ mA},$ | See Figure 14 | Full | | | | 0.3 | |
| ı | | V_{NC} or $V_{NO} = 1$ V, $V_{COM} = 1$ V to 3 V, or | Switch off. | 25°C | | -20 | 2 | 20 | |
| I _{NC(OFF)} , I _{NO(OFF)} | NC, NO off leakage current | V_{NC} or $V_{NO} = 3 \text{ V}, V_{COM} = 1 \text{ V}$ to 3 V, | See Figure 15 | Full | 3.6 V | -50 | | 50 | nA |
| I _{NC(PWROFF)} , | on leakage current | V_{NC} or $V_{NO} = 0$ to 3.6 V, | Switch off, | 25°C | 0 V | -1 | 0.2 | 1 | μА |
| I _{NO(PWROFF)} | | $V_{COM} = 3.6 \text{ V to 0},$ | See Figure 15 | Full | 0 V | -15 | | 15 | |
| | | V _{NC} or V _{NO} = 1 V, V _{COM} = | | 25°C | | -10 | 2 | 10 | |
| I _{NC(ON)} , I _{NO(ON)} | NC, NO on leakage current | Open, or V_{NC} or $V_{NO} = 3 \text{ V}, V_{COM} = \text{Open},$ | Switch on, See Figure 16 | Full | 3.6 V | -20 | | 20 | nA |
| | COM | V_{NC} or $V_{NO} = 3.6 \text{ V to 0}$, | Switch off, | 25° | 0.17 | -1 | 0.2 | 1 | |
| I _{COM(PWROFF)} | off leakage current | $V_{COM} = 0 \text{ to } 3.6 \text{ V},$ | See Figure 15 | Full | 0 V | -15 | | 15 | μА |
| | COM | V_{NC} or V_{NO} = Open, | Switch on, | 25°C | | -10 | 2 | 10 | |
| I _{COM(ON)} | on leakage current | $V_{COM} = 1 \text{ V}, \text{ or } V_{NC} \text{ or } V_{NO} = 0 \text{ open}, V_{COM} = 3 \text{ V},$ | See Figure 16 | Full | 3.6 V | -20 | | 20 | nA |
| DIGITAL INPU | UT (IN) | 10011 | | | | | | | |
| V _{IH} | Input logic high | | | Full | | 2.4 | | 5.5 | |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.8 | V |
| | 1 | V 55V 0 | | 25°C | 0.01/ | -2 | | 2 | |
| I_{IH} , I_{IL} | Input leakage current | $V_1 = 5.5 \text{ V or } 0$ | | Full | 3.6 V | -100 | | 100 | nA |
| DYNAMIC | | | | | | | | | |
| | | $V_{COM} = V_+,$ | $C_1 = 35 pF$, | 25°C | 3.3 V | 5 | 16 | 35 | |
| t _{ON} | Turnon time | $R_L = 50 \Omega,$ | See Figure 18 | Full | 3 V to 3.6 V | 3 | | 50 | ns |
| | | $V_{COM} = V_+,$ | $C_1 = 35 pF$, | 25°C | 3.3 V | 1 | 9 | 20 | |
| t _{OFF} | Turnoff time | $R_L = 50 \Omega,$ | See Figure 18 | Full | 3 V to 3.6 V | 1 | | 30 | ns |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.



Electrical Characteristics for 3.3-V Supply (continued)

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C to } 85^{\circ}\text{C (unless otherwise noted)}^{(1)}$

| | PARAMETER | TEST COI | NDITIONS | TA | V. | MIN | TYP | MAX | UNIT |
|--|---------------------------|--|---|------|-----------------|-----|------|-----|------|
| | | $V_{NC} = V_{NO} = V_+,$ | $C_L = 35 \text{ pF},$ | 25°C | 3.3 V | | 9 | | |
| t _{BBM} | Break-before-make time | $V_{NC} = V_{NO} = V_{+},$ $R_L = 50 \Omega,$ | See Figure 19 | Full | 3 V to 3.6 V | 1 | | 40 | ns |
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 3.3 V | | -11 | | рС |
| C _{NC(OFF)} , C _{NO(OFF)} | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch off, See Figure 17 | 25°C | 3.3 V | | 18 | | pF |
| $C_{NC(ON)}, \\ C_{NO(ON)}$ | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch on, See Figure 17 | 25°C | 3.3 V | | 55 | | pF |
| C _{COM(ON)} | COM ON capacitance | V _{COM} = V ₊ or GND, | Switch on, See Figure 17 | 25°C | 3.3 V | | 55 | | pF |
| Cı | Digital input capacitance | $V_I = V_+ \text{ or GND},$ | See Figure 17 | 25°C | 3.3 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, | Switch on, See Figure 20 | 25°C | 3.3 V | | 100 | | MHz |
| O _{ISO} | Off isolation | $R_L = 50 \Omega$, f = 1 MHz, | Switch off, See Figure 21 | 25°C | 3.3 V | | -64 | | dB |
| X _{TALK} | Crosstalk | $R_L = 50 \Omega$, f = 1 MHz, | Switch on, See Figure 22 | 25°C | 3.3 V | | -64 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega,$ $C_L = 50 pF,$ | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 3.3 V | 0 | .01% | | |
| SUPPLY | | • | | | • | | | ', | |
| | Docitive cumply current | $V_1 = V_+$ or GND, | Switch on or off | 25°C | 3.6 V | | 10 | 25 | n^ |
| I ₊ | Positive supply current | $v_{\parallel} = v_{+} \cup i \cup U,$ | SWILCH OH OF OH | Full | 3.0 V | | | 100 | nA |



6.7 Electrical Characteristics for 2.5-V Supply

| | PARAMETER | TEST CONDITIO | NS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|--|------------------------------|--|--|------|----------------------|-----|------|----------------|------|
| ANALOG SWIT | СН | | | | | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V ₊ | V |
| | D 1 011 11 | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ | Switch on, | 25°C | | | 1.8 | 2.5 | _ |
| r _{peak} | Peak ON resistance | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | 2.3 V | | | 2.7 | Ω |
| | 011 | V_{NO} or $V_{NC} = 1.8 \text{ V}$, | Switch on, | 25°C | 0.01/ | | 1.5 | 2 | 0 |
| r _{on} | ON-state resistance | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | 2.3 V | | | 2.4 | Ω |
| A = | ON-state resistance match | V_{NO} or $V_{NC} = 1.8 \text{ V}$, | Switch on, | 25°C | 221/ | | 0.15 | 0.2 | Ω |
| Δr_{on} | between channels | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | 2.3 V | | | 0.2 | 77 |
| | | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -8 \text{ mA},$ | Switch on, See Figure 14 | 25°C | | | 0.6 | | |
| r _{on(flat)} | ON-state resistance flatness | V_{NO} or $V_{NC} = 0.8 \text{ V}, 1.8 \text{ V},$ | Switch on, | 25°C | 2.3 V | | 0.6 | 1 | Ω |
| | | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | | | | 1 | |
| | | V_{NC} or $V_{NO} = 0.5 \text{ V}$, | | 25°C | | -20 | 2 | 20 | |
| I _{NC(OFF)} , I _{NO(OFF)} | NC, NO | V_{COM} = 0.5 V to 2.3 V, or V_{NC} or V_{NO} = 2.3 V, V_{COM} = 0.5 V to 2.3 V, | Switch off, See Figure 15 | Full | 2.7 V | -50 | | 50 | nA |
| I _{NC(PWROFF)} , | OFF leakage current | V_{NC} or $V_{NO} = 0$ to 3.6 V, | Switch off, | 25°C | | -1 | 0.1 | 1 | |
| I _{NO(PWROFF)} | | $V_{COM} = 3.6 \text{ V to } 0,$ | See Figure 15 | Full | 0 V | -10 | | 10 | μА |
| 1 | NC NO | V _{NC} or V _{NO} = 0.5 V, V _{COM} = Open, | Curitab an | 25°C | | -10 | 2 | 10 | |
| I _{NO(ON)} | NC, NO ON leakage current | or V_{NC} or $V_{NO} = 2.2 \text{ V}$, $V_{COM} = \text{Open}$, | Switch on, See Figure 16 | Full | 2.7 V | -20 | | 20 | nA |
| l | COM | V_{NC} or $V_{NO} = 2.7 \text{ V to } 0$, | Switch off, | 25° | 0 V | -1 | 0.1 | 10 | μА |
| ICOM(PWROFF) | OFF leakage current | $V_{COM} = 0$ to 2.7 V, | See Figure 15 | Full | 0 0 | -10 | | 20 | μΛ |
| | COM | V_{NC} or V_{NO} = Open, V_{COM} = 0.5 V, | Switch on, | 25°C | 0.7.1/ | -10 | 2 | 10 | ^ |
| I _{COM(ON)} | ON leakage current | V_{NC} or V_{NO} = Open, V_{COM} = 2.2 V, | See Figure 16 | Full | 2.7 V | -20 | | 20 | nA |
| DIGITAL INPUT | (IN) | | | | | | | I | |
| V _{IH} | Input logic high | | | Full | | 1.8 | | 5.5 | V |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.6 | V |
| 1 1 | Input lookago current | V _I = 5.5 V or 0 | | 25°C | 2.7 V | -2 | | 2 | nA |
| I _{IH} , I _{IL} | Input leakage current | V ₁ = 3.5 V 01 0 | | Full | 2.7 V | 20 | | 20 | ПА |
| DYNAMIC | | | | | | | | | |
| | | | | 25°C | 2.5 V | 5 | 22 | 40 | : |
| t _{ON} | Turnon time | $V_{\text{COM}} = V_+,$ $R_{\text{L}} = 50 \ \Omega,$ | C _L = 35 pF, See Figure 18 | Full | 2.3 V to 2.7 V | 5 | | 50 | ns |
| | | | | 25°C | 2.5 V | 2 | 6 | 35 | |
| • | Turnoff time | $V_{COM} = V_+,$ | $C_L = 35 \text{ pF},$ | 20 0 | 2.3 V | | | | ns |
| t _{OFF} | rumon ume | $R_L = 50 \Omega$, | See Figure 18 | Full | to | 2 | | 50 | 115 |
| | | | | 0500 | 2.7 V | 0 | 40 | 25 | |
| | | $V_{NC} = V_{NO} = V_+,$ | $C_L = 35 \text{ pF},$ | 25°C | 2.5 V | 2 | 13 | 35 | : |
| t _{BBM} | Break-before-make time | $R_L = 50 \Omega$ | See Figure 19 | Full | 2.3 V to 2.7 V | 2 | | 45 | ns |
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 2.5 V | | -7 | | pC |
| C _{NC(OFF)} , C _{NO(OFF)} | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch off, See Figure 17 | 25°C | 2.5 V | | 18 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch on, See Figure 17 | 25°C | 2.5 V | | 55 | | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{+} \text{ or GND},$ | Switch on, See Figure 17 | 25°C | 2.5 V | | 55 | | pF |
| C _I | Digital input capacitance | $V_1 = V_+ \text{ or GND},$ | See Figure 17 | 25°C | 2.5 V | | 2 | | pF |
| - | | | Switch on, | | | | • | | - |

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.



Electrical Characteristics for 2.5-V Supply (continued)

 $V_{+} = 2.3 \text{ V to } 2.7, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}^{(1)}$

| PARAMETER | | TEST C | TEST CONDITIONS | | | | MAX | UNIT |
|-------------------|---------------------------|---|--|------|-------|-------|-----|------|
| O _{ISO} | Off isolation | $R_L = 50 \Omega$, $f = 1 MHz$, | Switch off, See Figure 21 | 25°C | 2.5 V | -64 | | dB |
| X _{TALK} | Crosstalk | $R_L = 50 \Omega$, f = 1 MHz, | Switch on, See Figure 22 | 25°C | 2.5 V | -64 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega,$ $C_L = 50 \text{ pF},$ | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 2.5 V | 0.02% | | |
| SUPPLY | | | | • | | | | |
| | Docitivo cupply current | V – V or CND | Switch on or off | 25°C | 2.7 V | 10 | 20 | nΛ |
| 1+ | Positive supply current | $V_1 = V_+ \text{ or GND},$ | Switch on or on | Full | 2.7 V | · | 50 | nA |

6.8 Electrical Characteristics for 1.8-V Supply

 $V_{+} = 1.65 \text{ V to } 1.95 \text{ V}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}^{(1)}$

| | PARAMETER | TEST CONDITIO | NS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|---|-------------------------------|---|--|------|---------------------------|----------------|------|----------------|------|
| ANALOG SW | ITCH | | | | | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V ₊ | V |
| - | Peak ON resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ | Switch on, | 25°C | 1.65 | | 5 | | Ω |
| r _{peak} Peak ON resistance | | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | V | | | 15 | 12 |
| - | ON-state resistance | V_{NO} or $V_{NC} = 1.5 \text{ V}$, | Switch on, | 25°C | 1.65 | | 2 | 2.5 | Ω |
| r _{on} | OIV-State resistance | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | V | | | 3.5 | 12 |
| A.r. | ON-state resistance match | V_{NO} or $V_{NC} = 1.5 \text{ V}$, | Switch on, | 25°C | 1.65 | | 0.15 | 0.4 | Ω |
| $\Delta r_{\sf on}$ | between channels | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | V | | | 0.4 | 12 |
| | ON-state resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -8 \text{ mA},$ | Switch on, See Figure 14 | 25°C | 1.65 | | 5 | | |
| r _{on(flat)} | flatness | V _{NO} or V _{NC} = 0.6 V, 1.5 V, | Switch on, | 25°C | V | | 4.5 | | Ω |
| | | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | | | | | |
| | | V_{NC} or $V_{NO} = 0.3 \text{ V}$, | | 25°C | | - 5 | 2 | 5 | |
| I _{NC(OFF)} , I _{NO(OFF)} | NC, NO OFF leakage current | $V_{COM} = 0.3 \text{ V to } 1.65 \text{ V,}$ or V_{NC} or $V_{NO} = 1.65 \text{ V,}$ $V_{COM} = 0.3 \text{ V to } 1.65 \text{ V,}$ | Switch off, See Figure 15 | Full | 1.95 V | -20 | | 20 | nA |
| I _{NC(PWROFF)} | | V_{NC} or $V_{NO} = 0$ to 1.95 V, Switch off, | 25°C | 0 V | -1 | 0.1 | 1 | ^ | |
| I _{NO(PWROFF)} | | $V_{COM} = 1.95 \text{ V to 0},$ | See Figure 15 | Full | UV | - 5 | | 5 | μΑ |
| I _{NC(ON)} , | NC. NO | V_{NC} or $V_{NO} = 0.3 \text{ V}$, $V_{COM} = \text{Open}$, | Switch on. | 25°C | 1.95 | - 5 | 2 | 5 | |
| I _{NO(ON)} | ON leakage current | or V_{NC} or $V_{NO} = 1.65 \text{ V}$, $V_{COM} = \text{Open}$, | See Figure 16 | Full | V | -20 | | 20 | nA |
| laaausaass | COM | V_{NC} or $V_{NO} = 1.95 \text{ V to } 0$, | | 25° | 0 V | -1 | 0.1 | 7 | μА |
| ICOM(PWROFF) | OFF leakage current | $V_{COM} = 0 \text{ to } 1.95 \text{ V},$ | See Figure 15 | Full | O V | - 5 | | 5 | μА |
| | COM | V_{NC} or V_{NO} = Open, V_{COM} = 0.3 V, | Switch on, | 25°C | 1.95 | - 5 | 2 | 5 | nA |
| I _{COM(ON)} | ON leakage current | or V_{NC} or V_{NO} = Open, V_{COM} = 1.65 V, | See Figure 16 | Full | V | -20 | | 20 | |
| DIGITAL INPU | JT (IN) | | | 1 | | | | ' | |
| V _{IH} | Input logic high | | | Full | | 1.5 | | 5.5 | |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.6 | V |
| | Innut lookogo | V 55 V 07 0 | | 25°C | 1.95 | -2 | | 2 | ^ |
| I _{IH} , I _{IL} | Input leakage current | $V_1 = 5.5 \text{ V or } 0$ | | Full | V | 20 | | 20 | nA |
| DYNAMIC | | | | | | | | | |
| | | | | 25°C | 1.8 V | 10 | 35 | 70 | |
| t _{ON} | Turnon time | $V_{COM} = V_+,$ $R_L = 50 \Omega,$ | C _L = 35 pF, See Figure 18 | Full | 1.65 V to 1.95 V | 10 | | 75 | ns |

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.



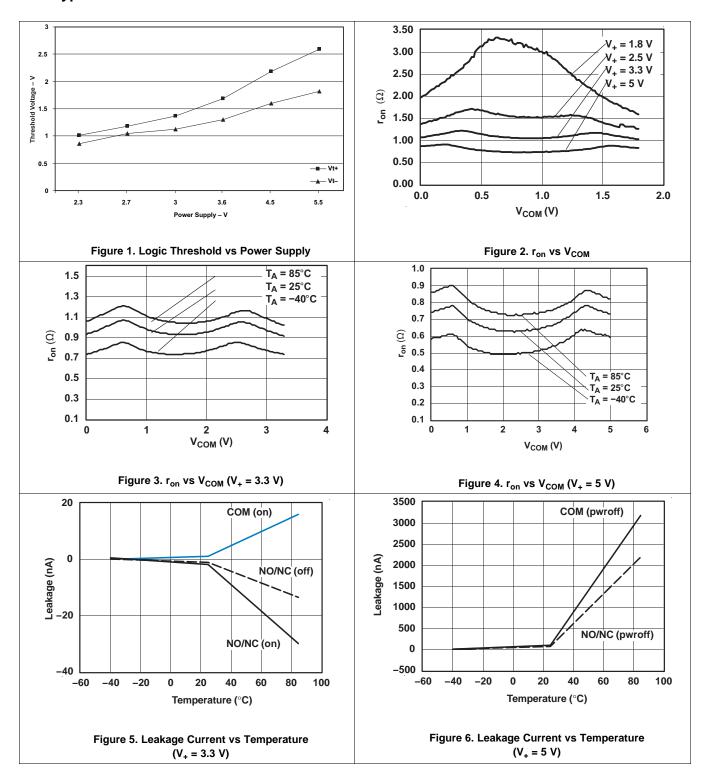
Electrical Characteristics for 1.8-V Supply (continued)

 V_{+} = 1.65 V to 1.95 V, T_{A} = -40°C to 85°C (unless otherwise noted)⁽¹⁾

| | PARAMETER | TEST CONI | DITIONS | T _A | V ₊ | MIN | TYP | MAX | UNIT |
|--|---------------------------|--|--|----------------|---------------------------|-----|-------|-----|------|
| | | | | 25°C | 1.8 V | 2 | 15 | 40 | |
| t _{OFF} | Turnoff time | $V_{COM} = V_{+},$ $R_{L} = 50 \ \Omega,$ | C _L = 35 pF, See Figure 18 | Full | 1.65 V to 1.95 V | 2 | | 50 | ns |
| | | | | 25°C | 1.8 V | | 22 | | |
| t _{BBM} | Break-before-make time | $\begin{split} V_{NC} &= V_{NO} = V_+, \\ R_L &= 50~\Omega, \end{split}$ | C _L = 35 pF, See Figure 19 | Full | 1.65 V to 1.95 V | 2 | | 70 | ns |
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 1.8 V | | -4 | | pC |
| C _{NC(OFF)} , C _{NO(OFF)} | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch off, See Figure 17 | 25°C | 1.8 V | | 18 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{+}$ or GND, | Switch on, See Figure 17 | 25°C | 1.8 V | | 55 | | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{+}$ or GND, | Switch on, See Figure 17 | 25°C | 1.8 V | | 55 | | pF |
| Cı | Digital input capacitance | $V_I = V_+ \text{ or GND},$ | See Figure 17 | 25°C | 1.8 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, | Switch on, See Figure 20 | 25°C | 1.8 V | | 105 | | MHz |
| O _{ISO} | Off isolation | $R_L = 50 \Omega$, f = 1 MHz, | Switch off, See Figure 21 | 25°C | 1.8 V | | 64 | | dB |
| X _{TALK} | Crosstalk | $R_L = 50 \Omega$, f = 1 MHz, | Switch on, See Figure 22 | 25°C | 1.8 V | | 64 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega,$ $C_L = 50 \text{ pF},$ | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 1.8 V | | 0.06% | | |
| SUPPLY | | ' | | | | | | | |
| | D 28 | V V OND | 0.11 | 25°C | 1.95 | | 5 | 15 | • |
| I ₊ | Positive supply current | $V_I = V_+ \text{ or GND},$ | Switch on or off | Full | V | | | 50 | μΑ |

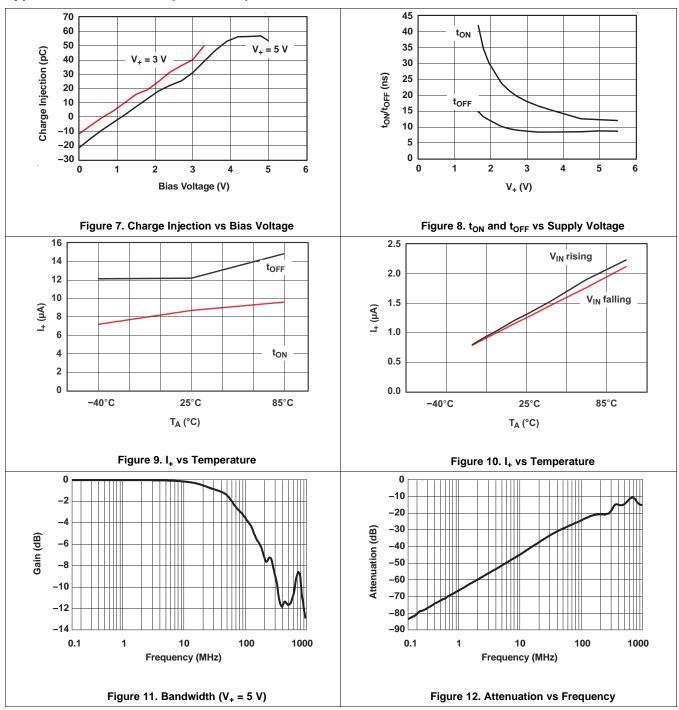


6.9 Typical Characteristics



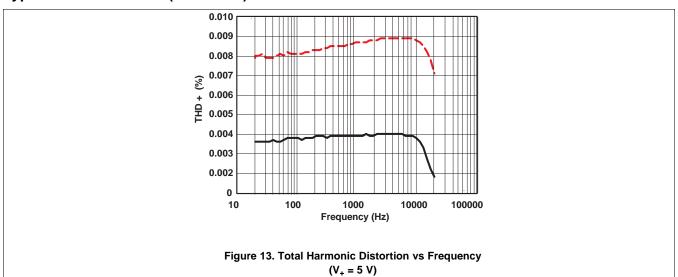


Typical Characteristics (continued)





Typical Characteristics (continued)



7 Parameter Measurement Information

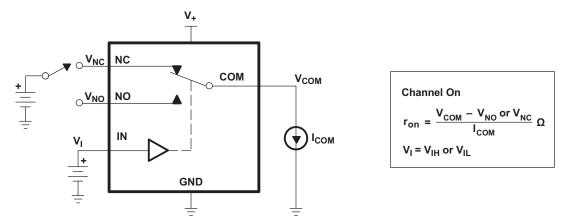
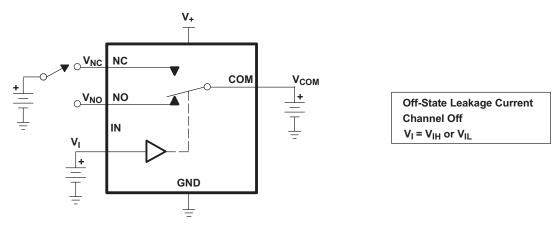


Figure 14. ON-State Resistance (ron)



 $\textbf{Figure 15. OFF-State Leakage Current (I}_{NC(OFF)}, I_{NC(PWROFF)}, I_{NO(OFF)}, I_{NO(PWROFF)}, I_{COM(OFF)}, I_{COM(PWROFF)})\\$

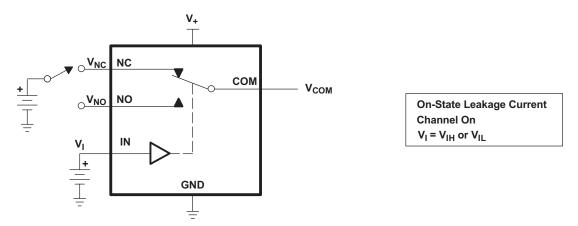


Figure 16. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)



Parameter Measurement Information (continued)

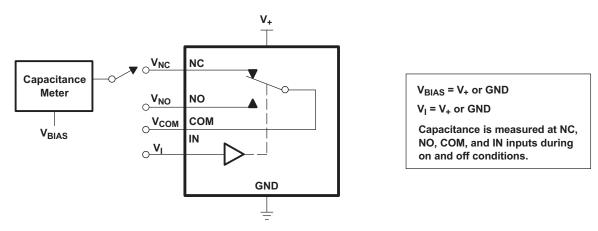
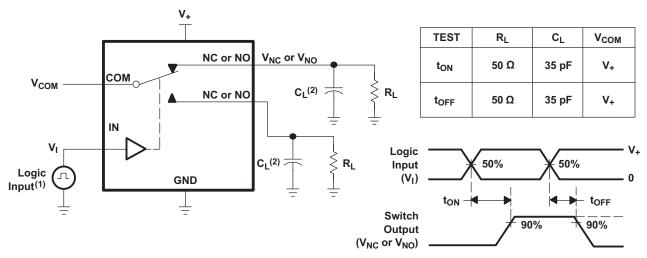


Figure 17. Capacitance (C_I, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)

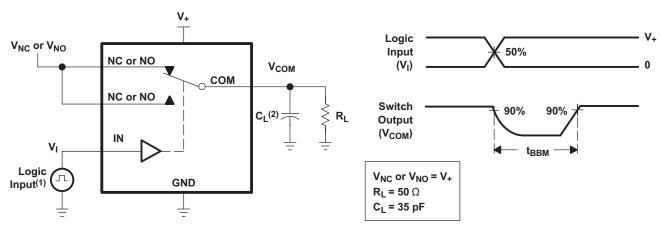


- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- (2) C_L includes probe and jig capacitance.

Figure 18. Turnon (t_{ON}) and Turnoff Time (t_{OFF})



Parameter Measurement Information (continued)



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- (2) C_L includes probe and jig capacitance.

Figure 19. Break-Before-Make Time (t_{BBM})

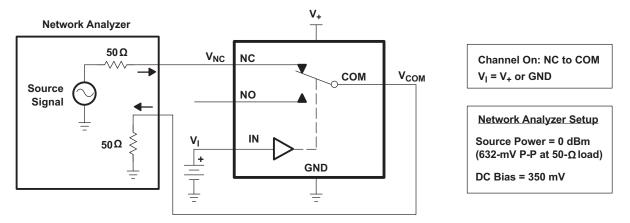


Figure 20. Bandwidth (BW)

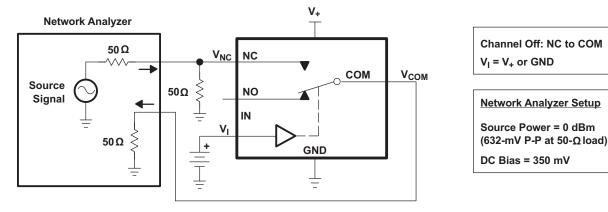


Figure 21. OFF Isolation (O_{ISO})



Parameter Measurement Information (continued)

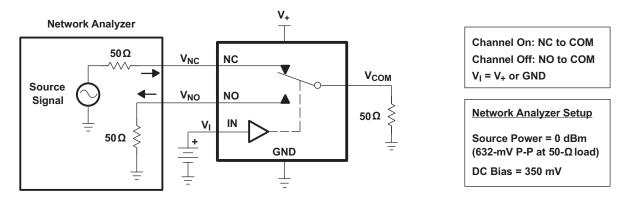
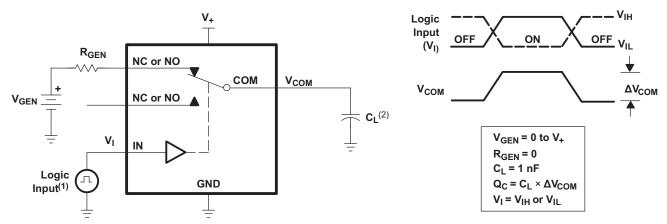
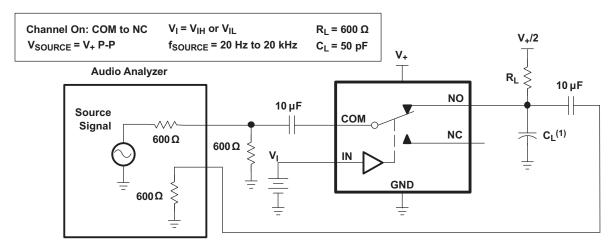


Figure 22. Crosstalk (X_{TALK})



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- (2) C_I includes probe and jig capacitance.

Figure 23. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)

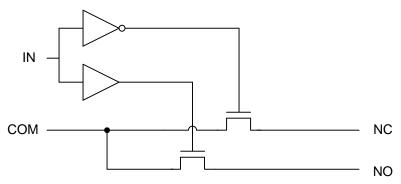
8 Detailed Description

8.1 Overview

The TS5A3159A is a single-pole-double-throw (SPDT) solid-state analog switch. The TS5A3159A, like all analog switches, is bidirectional. When powered on, each COM pin is connected to the NC pin. For this device, NC stands for *normally closed* and NO stands for *normally open*. If IN is low, COM is connected to NC. If IN is high, COM is connected to NO.

The TS5A3159A is a break-before-make switch. This means that during switching, a connection is broken before a new connection is established. The NC and NO pins are never connected to each other.

8.2 Functional Block Diagram



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8.3 Feature Description

The low ON-state resistance, ON-state resistance matching, and charge injection in the TS5A3159A make this switch an excellent choice for analog signals that require minimal distortion. In addition, the low THD allows audio signals to be preserved more clearly as they pass through the device.

The 1.65-V to 5.5-V operation allows compatibility with more logic levels, and the bidirectional I/Os can pass analog signals from 0 V to V₊ with low distortion.

8.4 Device Functional Modes

Table 1 lists the functional modes of the TS5A3159A.

Table 1. Function Table

| IN | NC TO COM, COM TO NC | NO TO COM, COM TO NO |
|----|-------------------------|-------------------------|
| L | ON | OFF |
| Н | OFF | ON |



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TS5A3159A can be used in a variety of customer systems. The TS5A3159A can be used anywhere multiple analog or digital signals must be selected to pass across a single line.

9.2 Typical Application

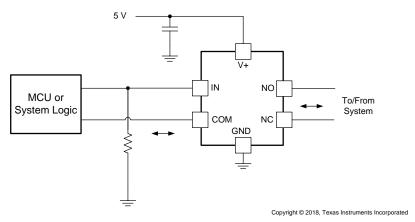


Figure 25. System Schematic for TS5A3159A

9.2.1 Design Requirements

In this particular application, V_+ was 5 V, although V_+ is allowed to be any voltage specified in *Recommended Operating Conditions*. A decoupling capacitor is recommended on the V+ pin. See *Power Supply Recommendations* for more details.

9.2.2 Detailed Design Procedure

In this application, IN is, by default, pulled low to GND. Choose the resistor size based on the current driving strength of the GPIO, the desired power consumption, and the switching frequency (if applicable). If the GPIO is open-drain, use pullup resistors instead.

9.2.3 Application Curve

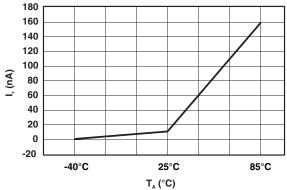


Figure 26. Power-Supply Current vs Temperature $(V_+ = 5 \text{ V})$



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μF bypass capacitor is recommended. If there are multiple pins labeled V_{CC} , then a 0.01- μF or 0.022- μF capacitor is recommended for each V_{CC} because the VCC pins are tied together internally. For devices with dual-supply pins operating at different voltages, for example V_{CC} and V_{DD} , a 0.1- μF bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1- μF and 1- μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

11 Layout

11.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self–inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Figure 27 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

Unused switch I/Os, such as NO, NC, and COM, can be left floating or tied to GND. However, the IN pin must be driven high or low. Due to partial transistor turnon when control inputs are at threshold levels, floating control inputs can cause increased I_{CC} or unknown switch selection states.

11.2 Layout Example

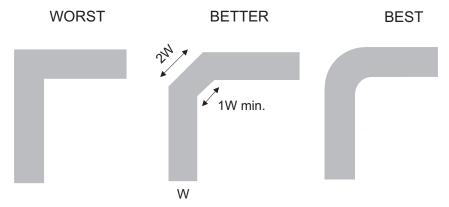


Figure 27. Trace Example

20



12 器件和文档支持

12.1 器件支持

12.1.1 器件命名规则

表 2. 参数 说明

| 符号 | 说明 |
|-----------------------------------|--|
| V _{COM} | COM 时的电压 |
| V_{NC} | NC 时的电压 |
| V_{NO} | NO 时的电压 |
| r _{on} | 通道打开时 COM 和 NC 或 COM 和 NO 端口之间的电阻 |
| r _{peak} | 额定电压范围的导通电阻峰值 |
| $\Delta r_{\sf on}$ | 通道间 ron 的差值 |
| r _{on(flat)} | 额定条件范围下,同一通道内 ron 最大值与最小值之间的差值 |
| I _{NC(OFF)} | 在输入和输出的最坏条件下,相应通道(NC 到 COM)处于关闭状态时,在 NC 端口测量的泄漏电流 |
| I _{NC(PWROFF)} | 在电源关闭状态下, $V_+=0$ 时,在 NC 端口测量的泄漏电流 |
| I _{NO(OFF)} | 在最不理想的输入和输出条件下,相应通道(NO 到 COM)处于关闭状态时,在 NO 端口测量的泄漏电流 |
| I _{NO(PWROFF)} | 在电源关闭状态下, $V_{+}=0$ 时,在 NO 端口测量的泄漏电流 |
| I _{NC(ON)} | 相应通道(NC 到 COM)处于开启状态且输出 (COM) 处于开放状态时,在 NC 端口测量的泄漏电流 |
| I _{NO(ON)} | 相应通道(NO到COM)处于开启状态且输出(COM)处于开放状态时,在NO端口测量的泄漏电流 |
| I _{COM(ON)} | 相应通道(COM 到 NO 或 COM 到 NC)处于开启状态且输出(NC 或 NO)处于开放状态时,在 COM 端口测量的泄漏电流 |
| I _{COM(PWROFF)} | 在电源关闭状态下, $V_+=0$ 时,在 COM 端口测量的泄漏电流 |
| V _{IH} | 控制输入 (IN) 逻辑高电平的最小输入电压 |
| V _{IL} | 控制输入 (IN) 逻辑低电平的最大输入电压 |
| VI | (IN) 时的电压 |
| I _{IH} , I _{IL} | 在 (IN) 测量的泄漏电流 |
| t _{ON} | 开关导通时间。此参数是在额定条件范围下,开关导通时,通过数字控制 (IN) 信号和模拟输出(COM、NC 或 NO)信号之间的传播延迟测量得出。 |
| toff | 开关关断时间。此参数是在额定条件范围下,开关关断时,通过数字控制 (IN) 信号和模拟输出(COM、NC 或 NO)信号之间的传播延迟测量得出。 |
| t _{BBM} | 先断后合时间。此参数是在额定条件范围下,控制信号改变状态时,通过两个相邻模拟通道(NC 和 NO)的输出之间的传播延迟测量得出。 |
| $Q_{\mathbb{C}}$ | 电荷注入是测量从控制 (IN) 输入到模拟(NC、NO、或 COM)输入产生的不需要的信号耦合的方法。电荷注入以库仑为单位,通过控制输入切换引起的总电荷测量得出。电荷注入, $Q_C=C_L\times\Delta V_O$, C_L 是负载电容, ΔV_O 是模拟输出电压的变化。 |
| C _{NC(OFF)} | 相应通道(NC 到 COM)关闭时 NC 端口的电容 |
| C _{NO(OFF)} | 相应通道(NO 到 COM)关闭时 NO 端口的电容 |
| C _{NC(ON)} | 相应通道(NC 到 COM)开启时 NC 端口的电容 |
| C _{NO(ON)} | 相应通道(NO 到 COM)开启时 NO 端口的电容 |
| C _{COM(ON)} | 相应通道(COM 到 NC 或 COM 到 NO)开启时 COM 端口的电容 |
| C _{IN} | (IN) 的电容 |
| O _{ISO} | 开关的关闭隔离是测量关闭状态开关阻抗的方法。关闭隔离以 dB 为单位,当相应通道(NC 到 COM 或 NO 到 COM)处于关闭状态时,在额定频率下测量得出。 |
| X _{TALK} | 串扰是测量从开启状态的通道到关闭状态的通道(NC 到 NO 或 NO 到 NC)产生的不必要信号耦合的方法。串扰在额定频率下测量得出且以 dB 为单位。 |
| BW | 开关的带宽。这是开启状态通道的增益中的频率 - 比 DC 增益低 3dB。 |
| T | 总谐波失真描述由模拟开关导致的信号失真。其定义为基础谐波的第二、第三或更高谐波与基础谐波的绝对幅度的比 |
| THD | 值或均方根 (RMS) 值。 |



12.2 文档支持

12.2.1 相关文档

请参阅如下相关文档:

《CMOS 输入缓慢变化或悬空的影响》, SCBA004

12.3 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商"按照原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的 《使用条款》。

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设计支持 71 参考设计支持 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

12.4 商标

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 静电放电警告



这些装置包含有限的内置 ESD 保护。 存储或装卸时,应将导线一起截短或将装置放置于导电泡棉中,以防止 MOS 门极遭受静电损伤。

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更,恕不另行通知和修订此文档。如欲获取此数据表的浏览器版本,请参阅左侧的导航。

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PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|----------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| TS5A3159ADBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | JAJR JAJH | Samples |
| TS5A3159ADBVT | OBSOLETE | SOT-23 | DBV | 6 | | TBD | Call TI | Call TI | -40 to 85 | (JAJK, JAJR) JAJH | |
| TS5A3159ADCKR | ACTIVE | SC70 | DCK | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | (JJK, JJR) JJH | Samples |
| TS5A3159ADCKT | OBSOLETE | SC70 | DCK | 6 | | TBD | Call TI | Call TI | -40 to 85 | (JJK, JJR) JJH | |
| TS5A3159AYZPR | ACTIVE | DSBGA | YZP | 6 | 3000 | RoHS & Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | JJN | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TS5A3159ADBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| TS5A3159ADCKR | SC70 | DCK | 6 | 3000 | 180.0 | 8.4 | 2.3 | 2.55 | 1.2 | 4.0 | 8.0 | Q3 |
| TS5A3159ADCKR | SC70 | DCK | 6 | 3000 | 180.0 | 8.4 | 2.41 | 2.41 | 1.2 | 4.0 | 8.0 | Q3 |
| TS5A3159AYZPR | DSBGA | YZP | 6 | 3000 | 178.0 | 9.2 | 1.02 | 1.52 | 0.63 | 4.0 | 8.0 | Q1 |



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*All dimensions are nominal

| 7 till dillitoriolorio di o riorriiridi | | | | | | | |
|---|---------------------|-----|------|------|-------------|------------|-------------|
| Device | Device Package Type | | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| TS5A3159ADBVR | SOT-23 | DBV | 6 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A3159ADCKR | SC70 | DCK | 6 | 3000 | 205.0 | 200.0 | 33.0 |
| TS5A3159ADCKR | SC70 | DCK | 6 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A3159AYZPR | DSBGA | YZP | 6 | 3000 | 220.0 | 220.0 | 35.0 |





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





DIE SIZE BALL GRID ARRAY



NOTES:

NanoFree Is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
 For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

 4. Falls within JEDEC MO-203 variation AB.





NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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